

**Data Sheet** 

9 kHz to 3 or 6 GHz



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# Optimized for manufacturing

On the path to faster throughput and greater uptime, the cost-effective EXG X-Series signal generators are optimized for manufacturing test. With analog and vector models, the EXG provides the signals you'll need for basic parametric testing of components and functional verification of receivers. Get "just enough" test at the right price with the EXG.

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### **Definitions and Conditions**

Specifications describe the performance of parameters covered by the product warranty and apply to the full temperature range of 0 to 55 °C, unless otherwise noted.

Typical describes additional product performance information that is not covered by the product warranty. It is performance beyond specifications that 80 percent of the units exhibit with a 95 percent confidence level over the temperature range 20 to 30 °C. Typical performance does not include measurement uncertainty.

Nominal values indicate expected performance, or describe product performance that is useful in the application of the product, but are not covered by the product warranty.

Measured describes an attribute measured during the design phase for purposes of communicating expected performance, such as amplitude drift vs. time. This data is not warranted and is measured at room temperature (approximately 25 °C).

The generator will meet its specifications when it has been stored at an ambient temperature within the allowed operating range for at least two hours before being turned on or if it had previously been stored at a temperature range inside the allowed storage range, but outside the allowed operating range.

### Frequency Specifications

Frequency range			
Frequency range	Option 501 (N5171B only)	9 kHz to 1 GHz	
	Option 503	9 kHz to 3 GHz	
	Option 506	9 kHz to 6 GHz	
Resolution	0.01 Hz		
Phase offset	Adjustable in nominal 0.1 ° inci	rements	
Frequency bands <sup>1</sup>			
	Band	Frequency range	N
	1	9 kHz to < 5 MHz	Digital synthesis
	1	5 to < 250 MHz	1
	2	250 to < 375 MHz	0.25
	3	375 to < 750 MHz	0.5
	4	750 to < 1500 MHz	1
	5	1500 to < 3000.001 MHz	2
	6	3000.001 to 6000 MHz	4
Frequency switching speed <sup>2, 3</sup>			
	Standard	Option UNZ <sup>4</sup>	Option UNZ, typical
CW mode			
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 950 µs
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 800 µs
Digital modulation on (N5172B only)			
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 1.05 ms
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 800 µs

<sup>1.</sup> N is a factor used to help define certain specifications within the document.

<sup>2.</sup> Time from receipt of SCPI command or trigger signal to within 0.1 ppm of final frequency or within 100 Hz, whichever is greater, and amplitude settled to within 0.2 dB from 20 to 30 °C. Implies simultaneous frequency and amplitude switching.

<sup>3.</sup> With internal channel corrections on, the frequency switching speed is < 1.3 ms, measured for list mode and SCPI mode cached frequency points. For the initial frequency point in SCPI mode the time is < 3.3 ms, measured. The instrument will automatically cache the most recently used 1024 frequencies. There is no speed degradation for amplitude-only changes.

<sup>4.</sup> Specifications apply when status register updates are off.

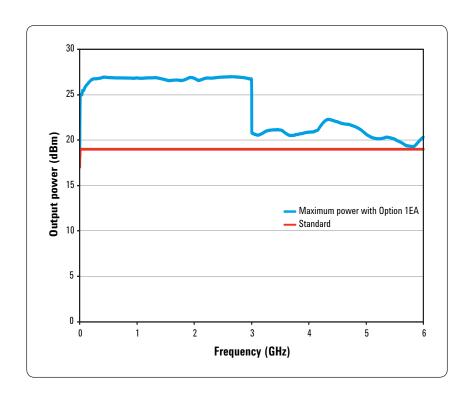
# aging rate # temperature effects # time voltage effects  Internal time base reference oscillator aging rate	Frequency reference	
Adjustment resolution		

<sup>1.</sup> Aging rate is determined by design as a function of the TCXO.

# **Amplitude Specifications**

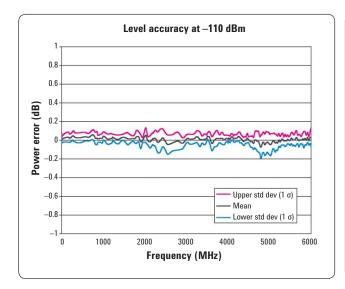
Output parameters			
Settable range	+30 to -144 dBm		
Resolution	0.01 dB, nominal		
Step attenuator	0 to 130 dB in 5 dB st	eps electronic type	
Connector	Type N 50 Ω, nomina		
Max output power <sup>1</sup>			
Frequency	Standard	Option 1EA	
9 kHz to 10 MHz	+13 dBm	+17 dBm	
> 10 MHz to 3 GHz	+18 dBm	+21 dBm	
> 3 to 6 GHz	+16 dRm	+18 dRm	

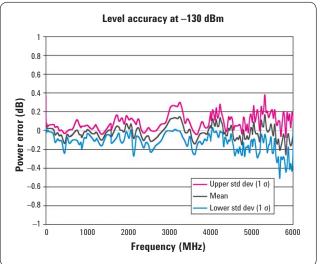
<sup>1.</sup> Quoted specifications between 20 °C and 30 °C. Maximum output power typically decreases by 0.01 dB/°C for temperatures outside this range.

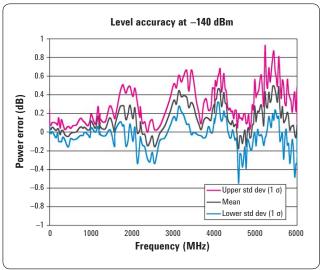


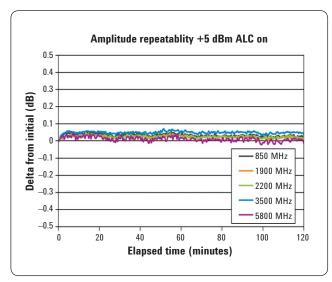
Absolute level accuracy in CV	V mode <sup>1</sup> (ALC on)				
External reference input	+21 to -60 dBm	< -60 to -110 dBm	< -110 to -127 dBm		
9 to 100 kHz	± 0.6 dB, typical	± 0.9 dB, typical			
100 kHz to 5 MHz	± 0.8 dB	± 0.9 dB			
> 5 MHz to 3 GHz	± 0.6 dB	± 0.8 dB	± 0.5 dB, typical		
> 3 to 6 GHz	± 0.6 dB	± 1.1 dB	± 0.6 dB, typical		
Absolute level accuracy in CW mode (ALC off, power search run, relative to ALC on)					
9 kHz to 6 GHz	± 0.15 dB, typical				
Absolute level accuracy in digital I/Q mode (N5172B only)					
(ALC on, relative to CW, W-CDMA 1 DPCH configuration < +10 dBm)					
9 kHz to 6 GHz	± 0.25 dB				

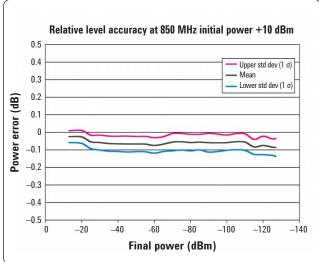
<sup>1.</sup> Quoted specifications between 20 °C and 30 °C. For temperatures outside this range, absolute level accuracy degrades by 0.01 dB/°C. Output power may drift up to .003 dB per g/kg change in absolute humidity (nom).





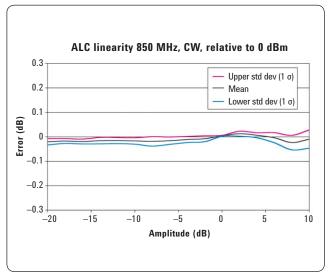


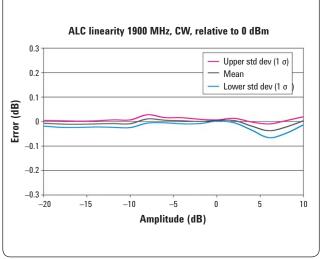




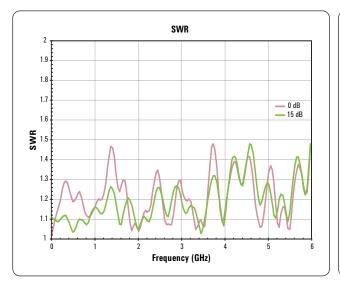
Repeatability measures the ability of the instrument to return to a given power setting after a random excursion to any other frequency and power setting. It should not be confused with absolute level accuracy.

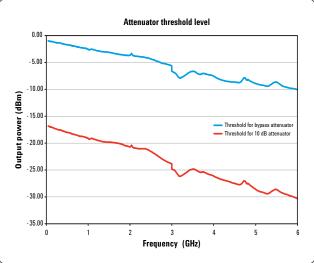
Relative level accuracy measures the accuracy of a step change from any power level to any other power level. This is useful for large changes (such as 5 dB steps).





SWR (measured CW mode)			
F		Attenuator state	
Frequency	Bypass	0 to 10 dB	15 dB or more
≤ 1.0 GHz	< 1.3:1	< 1.35:1	< 1.2:1
> 1.0 to 2 GHz	< 1.55:1	< 1:5:1	< 1.3:1
> 2 to 3 GHz	< 1.9:1	< 1.4:1	< 1.3:1
> 3 to 4 GHz	< 1.5:1	< 1.6:1	< 1.45:1
> 4 to 6 GHz	< 1.8:1	< 1.6:1	< 1.6:1



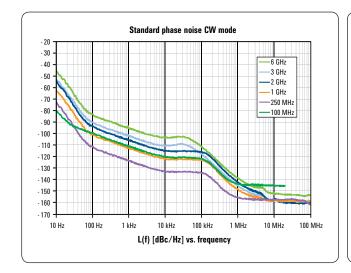


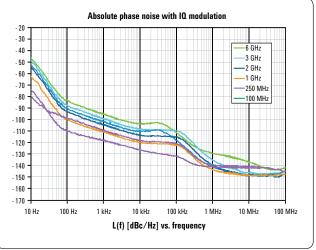
Maximum reverse power, nom	ninal			
< 1 GHz	50 W			
> 1 to < 2 GHz	25 W			
> 2 to < 6 GHz	20 W			
Max DC voltage	50 VDC			
Trip level	2 W			
Amplitude switching speed <sup>1</sup>	Standard	Option UNZ	Option UNZ, typical	
CW mode				
SCPI mode	≤ 5 ms, typical	≤ 750 µs	≤ 650 µs	
Power search SCPI mode	< 12 ms, measured			
List/step sweep mode	≤ 5 ms, typical	≤ 500 µs	≤ 300 µs	
Digital modulation on (N5172B only)				
SCPI mode	≤ 5 ms, typical	≤ 1.15 ms	≤ 950 µs	
Power search SCPI mode	< 12 ms, measured			
List/step sweep mode	≤ 5 ms, typical	≤ 900 µs	≤ 400 µs	
Alternate power level control	(N5172B only)			
Switching time (via waveform markers)	$20~\mu s$ within $\pm~1~dB$ , measured			
Functional power range	–15 dBm to –144 dBm, measi	ured		
User flatness correction				
Number of points	3201			
Number of tables	Dependent on available free memory in instrument; 10,000 maximum			
Entry modes	USB/LAN direct power meter control, LAN to GPIB and USB to GPIB, remote bus and manual USB/GPIB power meter control			
Sweep modes				
	See Frequency Specifications section for more detail			

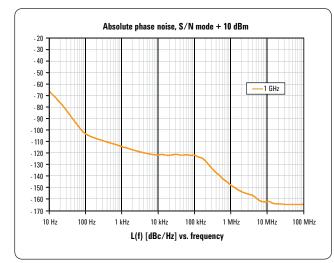
<sup>1.</sup> Time from receipt of SCPI command or trigger signal to amplitude settled within 0.2 dB. Switching speed specifications apply when status register updates are off.

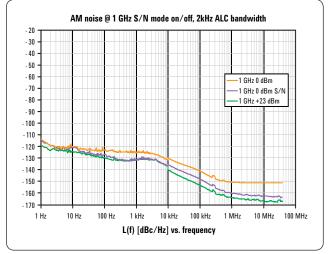
# **Spectral Purity Specifications**

Absolute SSB phase noise (dBc/Hz, CW at 20 kHz offset, typical)			
249 MHz	<b>–119</b>		
250 MHz	-133		
500 MHz	-128		
1 GHz	-122		
2 GHz	<b>–115</b>		
3 GHz	-110		
4 GHz	-109		
6 GHz	-103		









Harmonics (CW mode)		
Range	Standard < +4 dBm	Option 1EA < +12 dBm
9 kHz to 3 GHz	< -35 dBc	<-30 dBc
> 3 to 4 GHz	< –35 dBc, typical	< –35 dBc, typical
> 4 to 6 GHz	< –53 dBc, typical	< –40 dBc, typical
Nonharmonics (CW mode)		
Range	> 10 KHz offset	
	Standard (dBc)	
9 kHz to < 5 MHz	–65, nominal	
5 to < 250 MHz	<b>-75</b>	
250 to < 750 MHz	<b>-75</b>	
750 MHz to < 1.5 GHz	<b>-72</b>	
1.5 to < 3.0 GHz	-66	
3 to 6 GHz	-60	

Subharmonics (CW mode)				
· · · · · · · · · · · · · · · · · · ·				
9 kHz to 1.5 GHz	None			
> 1.5 to 3 GHz	-82 dBc			
> 3 to 6 GHz	-74 dBc			
Jitter <sup>1</sup>				
Carrier frequency	SONET/SDH data rate	rms jitter BW	μUI rms, measured	Seconds, typical
155 MHz	155 MB/s	100 Hz to 1.5 MHz	140	0.9 ps
622 MHz	622 MB/s	1 KHz to 5 MHz	67	0.11 ps
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	271	0.11 ps
Phase coherence (Option 012)				
LO input frequency range	250 MHz to 6 GHz, nomi	nal		
LO input power range	0 to +7 dBm, nominal			
LO output frequency range	250 MHz to 6 GHz, nomi	nal		
LO output power range	0 to +7 dBm, nominal			

<sup>1.</sup> Calculated from phase noise performance in CW mode at +10 dBm. For other frequencies, data rates, or bandwidths, please consult your sales representative.

# **Analog Modulation Specifications**

Frequency bands		
Band #	Frequency range	N
1	9 kHz to <5 MHz	1 (digital synthesis)
1	5 to < 250 MHz	1
2	250 to < 375 MHz	0.25
3	375 to < 750 MHz	0.5
4	750 to < 1500 MHz	1
5	1500 to < 3000.001 MHz	2
6	3000.001 to 6000 MHz	4
Frequency modulation (Option UN	T) (See N value above)	
Max deviation	N × 10 MHz, nominal	
Resolution	0.1% of deviation or 1 Hz, whichever is	greater, nominal
Deviation accuracy	< ± 2% + 20 Hz (1 kHz rate, deviation is	s N x 50 kHz)
Modulation frequency response	1 dB bandwidth	DC/5 Hz to 3 MHz, nominal
@ 100 KHz rate	3 dB bandwidth	DC/1 Hz to 7 MHz, nominal
Carrier frequency accuracy	$< \pm 0.2\%$ of set deviation + (N $\times$ 1 Hz) <sup>1</sup>	
Relative to CW in DCFM	$< \pm 0.06\%$ of set deviation + (N $\times$ 1 Hz).	, typical <sup>2</sup>
Distortion	< 0.4% [1 kHz rate, deviation is N x 50 k	(Hz]
FM using external inputs 1 or 2	Sensitivity	+1 V peak for indicated deviation, nominal
	Input impedance	50 $\Omega/600~\Omega/1~M~\Omega$ , nominal
	Paths	FM path 1 and FM path 2 are summed internally for composite modulation
Phase modulation (Option UNT) (S	See N value above)	
Maximum deviation	Normal bandwidth	N × 5 radians, nominal
	High-bandwidth mode	N × 0.5 radians, nominal
Frequency response	Normal bandwidth (3 dB)	DC to 1 MHz, nominal
	High-bandwidth mode (3 dB)	DC to 4 MHz, nominal
Resolution	0.1% of deviation	
Deviation accuracy	< + 0.5% + 0.01 rad, typical [1 kHz rate,	normal bandwidth mode]
Distortion	< 0.2% (typ) [1 kHz rate, deviation norm	al bandwidth mode]
ΦM using external inputs 1 or 2	Sensitivity	+1 V peak for indicated deviation, nominal
	Input impedance	50 $\Omega$ or 600 $\Omega$ or 1 M $\Omega$ , nominal
	Paths	$\Phi M$ path 1 and $\Phi M$ path 2 are summed internally for composite modulation

<sup>1.</sup> Specification valid for temperature changes of less than  $\pm$  5 °C since last DCFM calibration.

<sup>2.</sup> Typical performance immediately after a DCFM calibration.

AM depth type	Linear or e	Linear or exponential				
Maximum depth	100%	100%				
Depth resolution	0.1% of de	epth (nom)				
AM depth error	f < 5 MHz	f < 5 MHz < 1.5% of setting + 1% (typ 0.5% of setting + 1%)				б)
@1 KHz rate and < 80% depth	5 MHz ≤ f	≤ 2 GHz	< 3% of set	ting + 1 %		
	2 < f < 3 0	GHz	< 5% of set	< 5% of setting + 1% (typical 3% of setting + 1%)		
Total harmonic distortion	E . E MILL		30% depth	< 0.25%, ty	pical	
@ 1 KHz rate	F < 5 MHz	!	80% depth	< 0.5%, typ	ical	
	5 MHz ≤ f (2 to 3 GH	< 2 GHz z is typical)	30% depth	< 2%		
			80% depth	< 2%		
Frequency response	30% depth	n, 3 dB BW	DC/10 Hz to	50 KHz		
AM inputs using external inputs 1 or 2	Sensitivity	,	+1 V peak f 2.2 V peak)	or indicated dep	th (Over-range can l	oe 200% or
	Input impe	edance	50 Ω or 600	Ω or 1M Ω, Dan	nage level: ± 5 V max	(
	Paths	AM path 1 and AM path 2 are summed internally for composit modulation				y for composite
Wideband AM (N5172B only)	Rates ALC	off/on	DC/800 Hz	to 60 MHz, nomi	nal	
	Sensitivity	Sensitivity 0.25 V = 100% (I input + 0.5 V offset)				
	Input impe	edance	50 Ω, nomir	al (I input)		
Simultaneous and composit	e modulat	tion <sup>2</sup>				
Simultaneous modulation	All modula except: FN simultane generator,	ation types (IQ, F I and phase mod ously generated	lulation cannot be using the same mo n run concurrently	combined and tw dulation source	) may be simultaneo vo modulation types for example, the ba ulate the output RF (	cannot be seband I/Q
Composite modulation					h are summed interr f internal or external	
	AM	FM	Phase	Pulse	Internal IQ <sup>2</sup>	External IQ <sup>2</sup>
AM	+	+	+	+	+	+
FM	+	+		+	+	+
Phase	+	_	+	+	+	+
Pulse	+	+	+	_	+	+
Internal I/Q²	+	+	+	+	*	+
External IQ <sup>2</sup>	+	+	+	+	+	_

<sup>1.</sup> AM specifications apply 6 dB below maximum specified power from 20 to 30 °C.

<sup>2.</sup> IO modulation available on N5172B.

External modulation inputs	
	lation inputs; Option UNW required for pulse modulation inputs)
EXT1	AM, FM, PM
EXT2	AM, FM, PM
PULSE	Pulse (50 Ω only)
l I	Wideband AM (50 Ω only, N5172B only)
Input impedance	50 Ω, $1$ MΩ, $600$ Ω, DC and AC coupled
Standard internal analog modulation sour	ce
(Single sine wave generator for use with AM, FM, p	hase modulation requires Option UNT or 303)
Waveform	Sine
Rate range	0.1 Hz to 2 MHz (tunable to 3 MHz)
Resolution	0.1 Hz
Frequency accuracy	Same as RF reference source, nominal
LF audio output	0 to 5 V peak into 50 Ω, –5V to 5 V offset, nominal
Multifunction generator (Option 303)	
The multifunction generator option (Option 303) co simultaneously using the composite modulation fea	nsists of seven waveform generators that can be set independently with up to five atures in AM, FM/PM, and LF out
Waveform	
Function generator 1	Sine, triangle, square, positive ramp, negative ramp (pulse for LF out only)
Function generator 2	Sine, triangle, square, positive ramp, negative ramp (pulse for LF out only)
Dual function generator	Sine, triangle, square, positive ramp, negative ramp, phase offset, and amplitude ratio for Tone 2 relative to Tone 1
Swept function generator	Sine, triangle, square, positive ramp, negative ramp Trigger: free run, trigger key, bus, external, internal, timer trigger
Noise generator 1	Uniform, Gaussian
Noise generator 2	Uniform, Gaussian
DC	Only for LF output –5 V to +5 V, nominal
Frequency parameters	
Sine wave	0.1 Hz to 10 MHz, nominal
Triangle, square, ramp, pulse	0.1 Hz to 1 MHz, nominal
Noise bandwidth	10 MHz, nominal
Resolution	0.1 Hz
Frequency accuracy	Same as RF reference source, nominal
Narrow pulse modulation (Option UNW) 1	
On/off ratio	> 80 dB, typical
Rise/fall times (Tr, Tf)	< 10 ns; 7 ns, typical
Minimum pulse width ALC on/off	≥ 2 us/≥ 20 ns
Repetition frequency ALC on/off	10 Hz to 500 kHz/DC to 10 MHz
Level accuracy (relative to CW) ALC on/off <sup>2</sup>	< ± 1.0 dB/< ± 1.0 dB, typical

- 1. Pulse specifications apply to frequencies > 500 MHz. Operable down to 10 MHz.
- 2. With power search on.

Video feed-through $^1 \le 3GHz/> 3GHz$	< 50 mV, typical/< 5 mV, typical
Video delay (ext input to video)	30 ns, nominal
RF delay (video to RF output)	20 ns, nominal
Pulse overshoot	< 15%, typical
Input level	+1 Vpeak = RF on into 50 $\Omega$ , nominal
Td video delev (verieble)	

Td video delay (variable)

Tw video pulse width (variable)

Tp pulse period (variable)

Tm RF delay

Trf RF pulse width

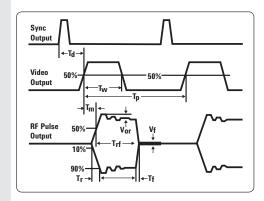
Tf RF pulse fall time

Tr RF pulse rise time

Vor pulse overshoot

Vf Video feedthrough

On/off time range



Internal pulse generator (included with Op	tion UNW)			
Modes	Free-run, square, triggered, adjustable doublet, trigger doublet, gated, and external pulse			
Square wave rate	0.1 Hz to 10 MHz, 0.1 Hz resolution, nominal			
Pulse period	30 ns to 42 seconds, nominal			
Pulse width	20 ns to pulse period –10 ns, nominal			
Resolution	10 ns			
Adjustable trigger delay	-pulse period + 10 ns to pulse period to pulse width -10 ns			
Settable delay	Free run	-3.99 to 3.97 μs		
	Triggered	0 to 40 s		
Resolution (delay, width, period)	10 ns, nominal			
Pulse doublets	1st pulse delay	(Relative to sync out) 0 to 42 s – pulse width – 10 ns		
	1st pulse width	500 ns to 42 s – delay – 10 ns		
	2nd pulse delay	0 to 42 s – (Delay 1 + Width 2) – 10 ns		
	2nd pulse width	20 ns to 42 s – (Delay 1 + Delay 2) – 10 ns		
Pulse train generator Option 320 (requires	Option UNW)			
Number of pulse patterns	2047			

6.000 000 000 00 GHz -10.00 dBn	Train Display Time Offset 0.00000000 sec
Time Offset: 0.000 000 00 Sec Pulse Train	Zoom In
	Zoom Out
0sec 1.00usec/div 4.90usec	Zoom In Max
*** PROTO CODE ** NOT FOR CUSTOMER USE *** OS/19/2010 OS:41	Zoom Out Max

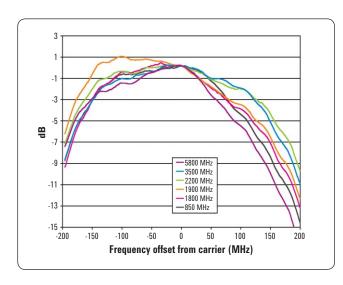
20 ns to 42 sec

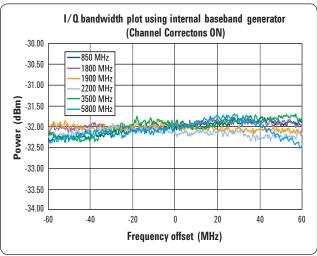
## **Vector Modulation Specifications**

### N5172B only

I/Q modulator external inputs		
Bandwidth	Baseband (I or Q)	Up to 100 MHz baseband, nominal
	RF (I+Q)	Up to 200 MHz RF, nominal
I or Q offset	± 100 mV	
I/Q gain	± 1 dB	
Quadrature angle adjustment	± 200 units	
Full scale input drive (I+Q)	0.5 V into 50 Ω, nomina	
Internal I/Q baseband generat	or adjustments <sup>2</sup> (Options	653 and 655)
I/Q offset	± 20%	(0.025% dB resolution)
I/Q gain	± 1 dB	(0.001 dB resolution)
Quadrature angle adjustment	± 10 °	(0.01 degrees resolution)
I/Q phase	± 360.00 °	(0.01 degrees resolution)
I/Q skew	± 500 ns	(1 picosecond resolution)
I/Q delay	± 250 ns	(1 picosecond resolution)
External I/Q outputs		
Impedance	50 Ω, nominal per outpu	ıt
	100 Ω, nominal different	tial output
Туре	Single-ended or differen	itial (Option 1 EL)
Maximum voltage per output	± 0.5 V peak-to-peak; in	to 50 Ω (200 uV resolution)
Bandwidth	Baseband (I or Q)	60 MHz, nominal (Option 653 and 655)
	RF (I+Q)	120 MHz, nominal (Option 653 and 655)
Amplitude flatness	± 0.2 dB measured with	channel corrections optimized for IQ output
Phase flatness	± 2.5 degrees measured	I with channel corrections optimized for IQ output
Common mode I/Q offset	± 1.5 V into 50 Ω (200 u	V resolution)
Differential mode I or Q offset	± 25 mV into 50 Ω (200	uV resolution)

- 1. I/O adjustments represent user intverface parameter ranges and not specifications.
- 2. Internal IQ adjustments apply to RF out and IQ outputs simultaneously.





Channels	2 [I and Q]		
Resolution	16 bits [1/65,536]		
Sample rate	Option 653	100 Sa/s to 75 MSa/s	
	Option 653 and 655	100 Sa/s to 150 MSa/s	
RF bandwidth	Option 653	60 MHz, nominal	
	Option 653 and 655	120 MHz, nominal	
nterpolated DAC rate	800 MHz		
requency offset range	± 60 MHz		
Digital sweep modes	In list sweep mode each point in the list can along with user definable frequencies and an Specifications sections for more detail.		
Waveform switching speed <sup>1</sup>	ann I	≤ 5 ms, measured (standard)	
	SCPI mode	≤ 1.2 ms, measured (Option UNZ)	
	11.77	≤ 5 ms, measured (standard)	
	List/step sweep mode	≤ 900 us, measured (Option UNZ)	
Waveform transfer rates	FTP LAN to internal SSD	10.7 MB/sec or 2.67 Msa/sec	
measured, no markers)	Internal SSD to FTP LAN	7.7 MB/sec 1.92 Msa/sec	
	FTP LAN to BBG	8.2 MB/sec or 2.05 Msa/sec	
	FTP LAN to BBG encrypted	4 MB/sec or 1 Msa/sec	
	USB to BBG	19 MB/sec or 4.75 Msa/sec	
	BBG to USB	1.2 MB/sec or 300 Ksa/sec	
	Internal SSD to BBG	48 MB/sec or 12 Msa/sec	
	BBG to internal SSD	1.2 MB/sec or 300 Ksa/sec	
	Removable SD card to baseband generator (C	Option 006)	
Arbitrary waveform memory		32 Msa (standard)	
	Maximum playback capacity	256 Msa (Option 021)	
		512 Msa (Option 022)	
		3 GBytes/800 Msa (standard)	
	Maximum storage capacity including markers	30 GBytes/7.5 Gsa (Option 009)	
		8 GBytes / 2 Gsa (Option 006)	
Vaveform segments		60 samples to 32 Msa (standard)	
	Segment length	60 samples to 256 Msa (Option 021)	
		60 samples to 512 Msa (Option 022)	
	Minimum memory allocation per segment	256 samples	
	Maximum number of segments	8192	
Naveform sequences	Maximum number of sequences	> 2000 depending on non-volatile memory usage	
	Maximum number of comments (comments	32,000 (standard)	
	Maximum number of segments/sequence	4 million (Option 021 or 022)	
	Maximum number of repetitions	65,535	

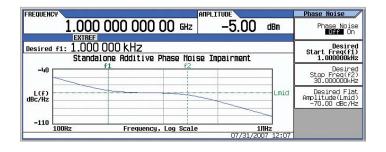
<sup>1.</sup> SCPI mode switching speed applies when waveforms are pre-loaded in list sweep and sample rate ≥ 10 MSa/s.

Triggers	Types		Continuous, single, gated, segment advance	
	Source		Trigger key, external, bus (GPIB, LAN, USB)	
		Continuous	Free run, trigger and run, reset and run	
	Mada	Single	No retrigger, buffered trigger, immediate retrigger	
	Modes	Gated	Negative polarity or positive polarity	
		Segment advance	Single or continuous	
	External coarse delay	time	5 ns to 40 s	
	External coarse delay	resolution	5 ns	
	Trigger latency (Single	trigger only)	356 ns + 1 sample clock period, nominal	
	Trigger accuracy (Sing	le trigger only)	± 2.5 ns, nominal	
Multi-baseband generator	Fan out		1 master and up to 15 slaves	
synchronization mode	Trigger repeatability		< 1 ns, nominal	
(multiple sources)	Trigger accuracy		Same as normal mode	
	Trigger latency		Same as normal mode	
	Fine trigger delay rang	е	See Internal IQ Baseband section	
	Fine trigger delay reso	lution	See Internal IQ Baseband section	
	IQ phase adjustment r	ange	See Internal IQ Baseband section	
Markers	panel; a marker can al		vaveform generation process, or from the front lanking, ALC hold functions, and alternate on	
	Marker polarity		Negative, positive	
	Number of markers		4	
	RF blanking/burst on/off ratio		> 80 dB	
	Alternate amplitude co	ontrol switching speed	See amplitude section	
Real-time baseband generator (0	Option 660)			
Real-time baseband generator required for real-time Signal Studio	Cellular real-time appli	cations	LTE-FDD, LTE-TDD, HSPA+/W-CDMA, GSM/EDGE, cdma2000®	
applications <sup>1</sup>	Real-time navigation		GPS, GLONASS	
	Real-time video applica	tions	DVB-T/T2/H/S/S2/C/J.83 Annex A/C, ISDB-T/	
	Note: Option 660 is not	required for real-time cus	tom modulation (Option 431)	
	Memory: Shares memo	ory with Options 653 and 6	S55	
	Triggering: Same as 0	ptions 653 and 655		
	Markers: 3 markers av	vailable, all other featur	es are same as Options 653 and 655	
AWGN (Option 403)				
Туре	Real-time, continuous	y calculated, and played	using DSP	
Modes of operation			rbitrary waveform or real-time baseband generator	
Bandwidth	With Option 653	0 1 7 7	1 Hz to 60 MHz	
	With Option 653 and 6	 55	1 Hz to 120 MHz	
Crest factor	15 dB			
Randomness		generation, repetition pe	eriod 313 x 10^9 years	
Carrier-to-noise ratio	± 100 dB when added		·	
Carrier-to-noise ratio formats	C/N, Eb/No	-		
Carrier-to-noise ratio error		dB at baseband I/Q out	puts	
1 See Signal Studio configuration assistant a		'		

<sup>1.</sup> See Signal Studio configuration assistant for more information.

	Mode (Option 431)		DDOK ODOK ODDOK (12000)	
Modulation	PSK		BPSK, QPSK, OQPSK, π/4DQPSK, gray coded and unbalanced QPSK, 8PSK, 16PSK, D8PSK	
	QAM		4, 16, 32, 64, 128, 256, 1024 (and 89600 VSA mappings)	
	FSK		Selectable: 2, 4, 8, 16, C4FM	
	MSK		0 to 100 °	
	ASK		0 to 100%	
Multicarrier	Number of carr	iers	Up to 100 (limited by a max bandwidth of 120 MHz depending on symbol rate and modulation type)	
	Frequency offset	(per carrier)	Up to -60 to +60 MHz	
	Power offset (p	er carrier)	0 dB to -40 dB	
Symbol rate	50 sps to 75 Ms	sps		
Filter types	Nyquist, root-N	yquist, Gaussian, rectan	gular, APCO 25 C4EM, user	
Quick setup modes	APCO 25w/C4F PHS, PWT, TET		Bluetooth®, CDPD, DECT, EDGE, GSM, NADC, PDC,	
Data	Random only			
Custom modulation real-	time mode (Option 43	31) (Does not require	e Option 660)	
Modulation	PSK	BPSK, QPSK, OQF 8PSK, 16PSK, D8F	K, π/4DQPSK, gray coded and unbalanced QPSK, K	
	QAM	4, 16, 32, 64, 128,	256, 1024 (and 89600 VSA mappings)	
		Selectable	2,4,8, 16 level symmetric, C4FM	
	FSK	User-defined	Custom map of up to 16 deviation levels	
		Max deviation	40 MHz	
	MSK	0 to 100 °		
	ASK	0 to 100%		
	Custom I/Q	Custom map of 10	024 unique values	
Frequency offset	Up to -60 MHz	to +60 MHz		
Symbol rate	Internal genera	ted data	1000 sps to 75 Msps and max of 10 bits per symbol (Option 653 + 655)	
	External serial	data	1000 sps to [(50 Mbits/sec)/(#bits/symbol)]	
Filter types	Selectable		Nyquist, root-Nyquist, Gaussian, rectangular, APCO 25 C4FM, IS-95	
	Custom FIR		16-bit resolution, up to 64 symbols long, automatically resampled to 1024 coefficients (max) > 32 to 64 symbol filter: symbol rate ≤ 12.5 MHz > 16 to 32 symbol filter: symbol rate ≤ 25 MHz Internal filters switch to 16 tap when symbol rate is between 25 and 75 MHz	
Quick setup modes		-M, APCO25 w/CQPSK, T, WorldSpace, Iridium, I	TETRA , Bluetooth, CDPD, DECT, EDGE, GSM, NADC, CO, CT2, TFTS	
Trigger delay	Range		0 to 1,048,575 bits	
	Resolution		1 bit	

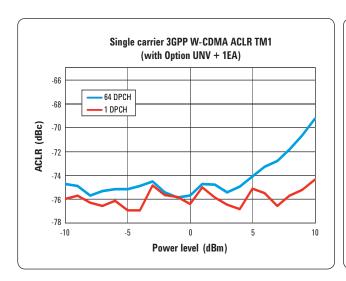
Data types	Internally generated	Pseudo-random patterns	PN9, PN11, PN15, PN20, PN23	
	Internally generated	Repeating sequence	Any 4-bit sequence	
			32 Mb (standard)	
		Direct-pattern RAM [PRAM] max size  Note: Used for custom TDMA/non-standard framing		
	Note. Osed for custom 1010	IA/ Holf-Standard Hailing	1024 Mb (Option 022)	
			32 MB (standard)	
	User file		256 MB (Option 021)	
			512 MB (Option 022)	
		Туре	Serial data	
	Externally streamed data	Inputs/outputs	Data, symbol sync, bit clock (output only)	
Internal burst shape	Rise/fall time range	Rise/fall time range		
(varies with bit rate)	Rise/fall delay range		–15 to +15 bits	
Multitone and two-tone (Option	า 430)			
Number of tones	2 to 64, with selectable on/	off state per tone		
Frequency spacing	100 Hz to 120 MHz (with Op	tion 653 and 655)		
Phase (per tone)	Fixed or random			
Real-time phase noise impairm	ents (Option 432)			
Close-in phase noise characteristics	–20 dB per decade			
Far-out phase noise characteristics	-20 dB per decade			
Mid-frequency characteristics	Start frequency (f1)	Offset settable from 0 to 77	MHz	
	Stop frequency (f2)	Offset settable from 0 to 77	MHz	
Phase noise amplitude level (L(f))	User selected; max degrada	tion dependent on f2		

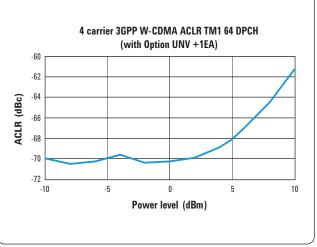


3GPP W-CDMA distortion performance 1,2								
			Standard		Option U	NV	Option U with Opt	
	Power level		≤ 2 dBm <sup>2</sup>	!	≤ 2 dBm	2	≤ 5 dBm <sup>2</sup>	2
Offset	Configuration	Frequency	Spec	Тур	Spec	Тур	Spec	Тур
Adjacent (5 MHz)	- 1 DPCH. 1 carrier	1800 to 2200 MHz	$-69~\mathrm{dBc}$	-73 dBc	-71 dBc	-75 dBc	-71 dBc	-75 dBc
Alternate (10 MHz)	T DECH, I Calliel	1000 to 2200 NITZ	-70 dBc	-75 dBc	-72 dBc	-77 dBc	-71 dBc	–77 dBc
Adjacent (5 MHz)	Test model 1 with	1800 to 2200 MHz	-68 dBc	-70 dBc	-71 dBc	-73 dBc	-71 dBc	-72 dBc
Alternate (10 MHz)	64 DPCH, 1 carrier	TOUU LU ZZUU IVIHZ		-73 dBc	-72 dBc	-76 dBc	-71 dBc	-76 dBc
Adjacent (5 MHz)	Test model 1 with	1800 to 2200 MHz	-63 dBc	-65 dBc	-65 dBc	-67 dBc	-64 dBc	-66 dBc
Alternate (10 MHz)	64 DPCH, 4 carrier	1000 10 2200 10172	-64 dBc	-66 dBc	-66 dBc	-68 dBc	-66 dBc	-68 dBc

<sup>1.</sup> ACPR specifications apply when the instrument is maintained within  $\pm$  20 to 30 °C.

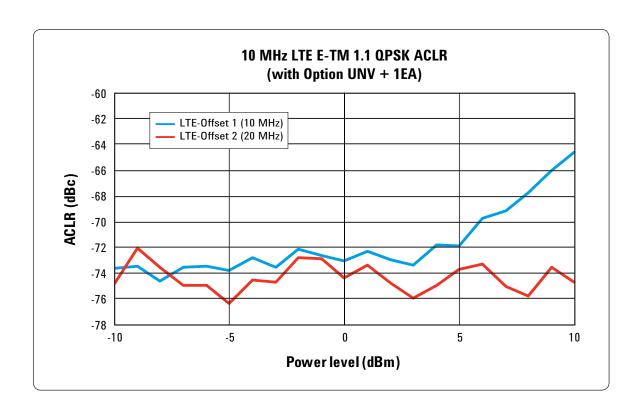
<sup>2.</sup> This is rms power. Convert from rms to peak envelope power (PEP) with the following equation: PEP = rms power + crest factor (for example, 3GPP test model 1 with 64 DPCH has a crest factor 11.5 dB, therefore at +5 dBm rms, the PEP = 5 dBm + 11.5dB = +16.5 dBm PEP).





3GPP LTE-FDD o	listortion perform	nance <sup>1</sup>							
			Standard	l	Option U	NV	Option U with Opt		
	Power level		≤ 2 dBm²		≤ 2 dBm	≤ 2 dBm²		≤ <b>5</b> dBm²	
Offset	Configuration	Frequency	Spec	Тур	Spec	Тур	Spec	Тур	
Adjacent (10 MHz) <sup>3</sup>	10 MHz E-TM 1.1	1800 to 2200 MHz	-64 dBc	-66 dBc	-67 dBc	-69 dBc	-64 dBc	-67 dBc	
Alternate (20 MHz) <sup>3</sup>	QPSK	1000 10 2200 10172	-66 dBc	-68 dBc	-69 dBc	-71 dBc	-69 dBc	-71 dBc	

- 1. ACPR specifications apply when the instrument is maintained within  $\pm$  20 to 30 °C.
- 2. This is rms power. Convert from rms to peak envelope power with the following equation: PEP = rms power + crest factor (for example, 3GPP test model 1 with 64 DPCH has a crest factor 11.5 dB, therefore at +5 dBm rms, the PEP = 5 dBm + 11.5 dB = +16.5 dBm PEP).
- 3. ACPR measurement configuration: reference channel integration BW: 9.015 MHz, offset channel integration bandwidth: 9.015 MHz.



GSM/EDGE output RF spectrum (ORFS)						
			GSM		EDGE	
	Power level		< +7 dBm		< +7 dBm	
Offset	Configuration	Frequency <sup>1</sup>	Standard, typical	Option UNV, typical	Standard, typical	Option UNV, typical
200 kHz			-34 dBc	−36 dBc	−37 dBc	–38 dBc
400 kHz	1 1	000 - 000 MIL	-69 dBc	–70 dBc	-69 dBc	-70 dBc
600 kHz	1 normal timeslot, - bursted	800 to 900 MHz 1800 to 1900 MHz	-81 dBc	-82 dBc	-80 dBc	-81 dBc
800 kHz	- burotou	1000 10 1000 10112	-82 dBc	-83 dBc	-82 dBc	-83 dBc
1200 kHz			-84 dBc	-85 dBc	-83 dBc	-84 dBc
3GPP2 cdma200	0 distortion perfo	ormance, typical				
			Standard	Option UNV	Option UNV +	1EA
Powe	r level <sup>2</sup>		Standard ≤ 2dBm	Option UNV ≤ 2 dBm	Option UNV + ≤ 5 dBm	· 1EA
Power	r level <sup>2</sup> Configuration	Frequency (1)			•	1EA
	Configuration	Frequency (1)	≤ 2dBm	≤ 2 dBm	≤ 5 dBm	1EA
Offset	Configuration 9 channel forward	Frequency (1) 800 to 900 MHz	≤ 2dBm Typical	≤ 2 dBm Typical	≤ 5 dBm Typical	1EA
Offset 885 kHz to 1.98 MHz	Configuration		≤ <b>2dBm Typical</b> –78dBc	≤ 2 dBm  Typical  -79dBc	≤ <b>5 dBm Typical</b> -77dBc	1EA
Offset 885 kHz to 1.98 MHz > 1.98 to 4.0 MHz > 4.0 to 10 MHz	Configuration  9 channel forward - link		≤ 2dBm  Typical  -78dBc  -86dBc  -91dBc	≤ 2 dBm  Typical  -79dBc  -87dBc	≤ <b>5 dBm</b> Typical  -77dBc  -87dBc	1EA
Offset 885 kHz to 1.98 MHz > 1.98 to 4.0 MHz > 4.0 to 10 MHz	Configuration  9 channel forward - link	800 to 900 MHz	≤ 2dBm  Typical  -78dBc  -86dBc  -91dBc	≤ 2 dBm  Typical  -79dBc  -87dBc	≤ <b>5 dBm</b> Typical  -77dBc  -87dBc	
Offset 885 kHz to 1.98 MHz > 1.98 to 4.0 MHz > 4.0 to 10 MHz 802.16e Mobile W	Configuration  9 channel forward  link  /iMAX™ distortion	800 to 900 MHz	≤ 2dBm  Typical  -78dBc  -86dBc  -91dBc  ured	≤ 2 dBm  Typical  -79dBc  -87dBc  -93dBc	≤ 5 dBm  Typical  -77dBc  -87dBc  -93dBc	

<sup>1.</sup> Performance evaluated at bottom, middle, and top of bands shown.

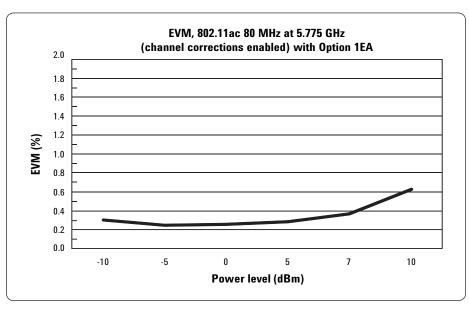
<sup>2.</sup> This is rms power. Convert from rms to peak envelope power (PEP) with the following equation: PEP = rms power + crest factor (for example: 3GPP test model 1 with 64 DPCH has a crest factor > 11 dB, therefore at +5 dBm rms the PEP = 5 dBm + 11 dB = +16 dBm PEP).

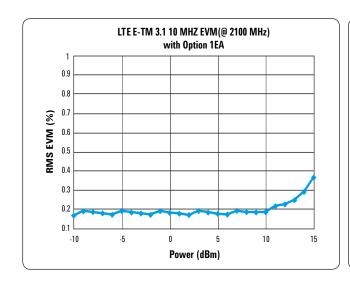
<sup>3.</sup> Measurement configuration: reference channel integration BW: 9.5 MHz, offset channel integration BW: 9 MHz, channel offset: 10 MHz.

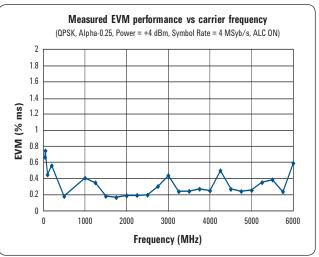
<sup>4. 802.16</sup>e WiMAX signal configuration—bandwidth: 10 MHz, FFT: 1024, frame length: 5 ms, guard period: 1/8, symbol rolloff: 5%, content: 30 symbols of PN9 data.

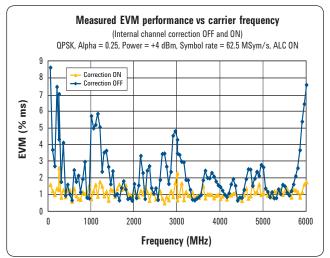
EVM performance data 1, 2										
Format	GSM		EDGE		cdma2000/1xEV-DO		W-CDMA		LTE FDD <sup>3</sup>	
Modulation type	GMSK (bursted)		3pi/8 8PSK (bursted)		QPSK		QPSK		64 QAM	
Modulation rate	270.833 ksps		70.833 ksps		1.2288 Mcps		3.84 Mcps		10 MHz	BW
Channel configuration	1 timeslot		1 timeslot		Pilot channel		1 DPCH		E-TM 3.	1
Frequency <sup>4</sup>	800 to 900 MHz 1800 to1900 MHz		800 to 900 MHz 1800 to 1900 MHz		800 to 900 MHz 1800 to 1900 MHz		1800 to 2200 MHz		1800 to	2200 MHz
EVM power level	≤ 7 dBm		≤7 dBm		≤ 7 dBm		≤ 7 dBm		≤ 7 dBm	
EVM power level with Option 1EA	≤ 13 dBm		≤ 13 dBm		≤ 13 dBm		≤ 13 dBm		≤ 13 dBm	
EVM/global phase error	Spec	Туре	Spec	Туре	Spec	Туре	Spec	Туре	Me	asured
	ms 0.8 ° peak 1.5 °	0.2 ° 0.6 °	1.2%	0.75%	1.3%	0.8%	1.2%	0.8%	(	0.2%
Format	802.11a/g	802.16e WiMAX <sup>5</sup>	QPSK			16 QAM				
Modulation type	64 QAM	64 QAM	QPSK 16 QAM							
Modulation rate	54 Mbps	10 MHz BW	4 Msps (root-Nyquist filter α = 0.25)							
Frequency 4	2400 to 2484 MHz 5150 to 5825 MHz	2300 to 2690 MHz 3300 to 3800 MHz	- ≤ 3 GHz		≤ 6 GHz ≤ 3 GHz		GHz	≤ 6 GHz		
EVM power level	≤ –5 dBm	≤ 2 dBm	≤ 4 dBm		≤ 4 dBm		≤ 4 dBm		≤	4 dBm
EVM power level with Option 1EA	≤ 2 dBm	≤8 dBm	≤ 10 dBm		≤ 10 dBm		≤ 10 dBm		≤ 1	0 dBm
EVM	Measured	Measured	Spec	Туре	Spec	Туре	Spec	Туре	Spec	Туре
	0.3%	0.3%	1.2%	0.8%	1.9%	1.1%	1.1%	0.65%	1.5%	0.9%

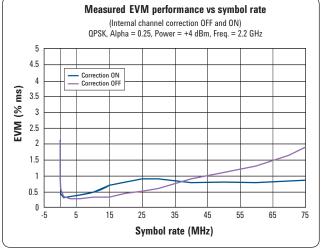
- 1. EVM specifications apply for the default ARB file setup conditions with the default ARB files supplied with the instrument.
- 2. EVM specifications apply after execution of I/Q calibration when the instrument is maintained within  $\pm$  5 °C of the calibration temperature.
- 3. LTE FDD E-TM 3.1,10 MHz, 64 QAM PDSCH, full resource block. Measured EVM after DC calibration.
- 4. Performance evaluated at bottom, middle, and top of bands shown.
- 5. 802.16e WiMAX signal configuration—bandwidth: 10 MHz, FFT: 1024, frame length: 5 ms, guard period: 1/8, symbol rolloff: 5%, content: 30 symbols of PN9 data.











### **General Specifications**

Remote programming	
Interfaces	GPIB IEEE-488.2, 1987 with listen and talk LAN 1000BaseT LAN interface, LXI Class C compliant USB Version 2.0
Control languages	SCPI Version 1997.0
Compatibility languages	Agilent Technologies: N5181A\61A, N 5182A\62A, N5183A, E4438C, E4428C, E442xB, E443xB, E8241A, E8244A, E8251A, E8254A, E8247C, E8257C/D, E8267C/D, 8648 Series, 8656B, E8663B, 8657A/B
	Aeroflex Inc.: 3410 Series
	Rohde & Schwarz: SMB100A, SMBV100A, SMA100A, SMU200A, SMJ100A, SMATE200A, SMIQ, SML, SMV

#### Power requirements

100-120 VAC, 50/60/400 Hz 220-240 VAC, 50/60 Hz 160 W maximum (N5171B) 300 W maximum (N5172B)

#### Operating temperature range

0 to 55 °C

#### Storage temperature range

–40 to 70 °C

#### Operating and storage altitude

Up to 15,000 feet

#### **Environmental stress**

Samples of this product have been type tested in accordance with the Agilent Environmental Test Manual and verified to be robust against the environmental stresses of storage, transportation and end-use; those stresses include but are not limited to temperature, humidity, shock, vibration, altitude, and power line conditions; test methods are aligned with IEC 60068-2 and levels are similar to MIL-PRF-28800F Class 3

#### Safety

Complies with European Low Voltage Directive 2006/95/EC

<ul> <li>IEC/EN 61010-1, 2nd Edition</li> </ul>	Acoustic noise emission	Geraeuschemission
<ul> <li>Canada: CSA C22.2 No. 61010-1</li> </ul>	LpA < 70 dB	LpA < 70 dB
<ul> <li>USA: UL std no. 61010-1, 2nd Edition</li> </ul>	Operator position	Am Arbeitsplatz
German Acoustic statement	Normal position	Normaler Betrieb
	Per ISO 7779	Nach DIN 45635 t.19

#### **EMC**

Complies with European EMC Directive 2004/108/EC

<ul> <li>IEC/EN 61326-1 or IEC/EN 61326-2-1</li> <li>CISPR Pub 11 Group 1, class A</li> </ul>	This ISM device complies with Canadian ICES-001; cet appareil ISM est conforme a la norme NMB-001 du Canada
<ul><li>AS/NZS CISPR 11</li><li>ICES/NMB-001</li></ul>	

#### Memory

- · Memory is shared by instrument states, user data files, sweep list files, waveform sequences, and other files
- 2 GB (30 GB with Option 009) memory available in the N5172B
- · Security Option 006 allows storage of up to 8 GB
- Depending on how the memory is utilized, a maximum of 1000 instrument states can be saved

#### Security (Option 006)

- · Removable 8 GB solid state memory (SD card) from rear panel
- User can force all files to be stored only on external memory card including instrument states, user data files, sweep list files, waveforms, waveform sequences, and other files.
- · Memory sanitizing, memory sanitizing on, power on, and display blanking
- · Disable USB ports

Note: Read/write speeds to external memory card will be slower compared to internal solid-state drive (Option 009)

#### Self-test

Internal diagnostic routines test most modules in a preset condition; for each module, if its node voltages are within acceptable limits, the module passes the test

#### Weight

N5171B:  $\leq$  13.6 kg (30 lb) net,  $\leq$  28.6 kg (63 lb.) shipping N5172B:  $\leq$  15.9 kg (35 lb) net,  $\leq$  30.8 kg (68 lb.) shipping

#### **Dimensions**

88 mm H x 458 mm W x 508 mm L (3.46 in H x 18 in W x 20 in L)

#### Recommended calibration cycle

36 months

#### ISO compliant

This instrument is manufactured in an ISO-9001 registered facility in concurrence with Agilent Technologies' commitment to quality.

# Inputs and Outputs

Front panel connectors	
RF output	Outputs the RF signal via a precision N type female connector; see output section for reverse power protection information
I and Q inputs	BNC input accepts "in-phase" and "quadrature" input signals for I/Q modulation; nominal input impedance is 50 $\Omega$ , damage levels are 1 Vrms and 5 Vpeak
USB 2.0	Used with a memory stick for transferring instrument states, licenses and other files into or out of the instrument; also used with U2000 Series USB average power sensors For a current list of supported memory sticks, visit www.agilent.com/find/X-series_SG, click on Technical Support, and refer to FAQs: Waveform Downloads and Storage
Rear panel connectors	
Rear panel inputs and outputs are 3.3 V C voltage levels	MOS, unless indicated otherwise; CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL
RF output (Option 1EM)	Outputs the RF signal via a precision N type female connector
I and Q inputs (Option 1EM)	Accepts "in-phase" and "quadrature" input signals for I/Q modulation SMB connector nominal input impedance is 50 $\Omega$ ; damage levels are 1 Vrms and 5 Vpeak; Option 1EM and N5162A units will come with 2 SMB to BNC adapters
I and ${\bf Q}$ outputs	BNC outputs the analog I/Q modulation signals from the internal baseband generator; nominal output impedance 50 $\Omega$ , DC coupled; damage levels $\pm$ 2 V
I bar and Q bar outputs (Option 1EL)	BNC outputs the complement of the I and Q signals for differential applications;
DAC Clk In (Option 012)	Reserved for future use.
Event 1	This connector outputs the programmable timing signal generated by marker 1 The marker signal can also be routed internally to control the RF blanking and ALC holfunctions; this signal is also available on the AUX I/O connector This output is TTL and 3.3 V CMOS compatible Damage levels are $> +8$ V and $< -4$ V
Pattern trigger	Accepts signal to trigger internal pattern generator to start single pattern output, for use with the internal baseband generators  Accepts CMOS signal with minimum pulse width of 10 ns  Female BNC  Damage levels are > +8 V and < -4 V
BBTRIG 1	Reserved for arbitrary and real-time baseband generators I/O such as Markers or trigger inputs
BBTRIG 2	Reserved for arbitrary and real-time baseband generators I/O such as Markers or trigger inputs
Sweep out	Generates output voltage, 0 to +10 V when the signal generator is sweeping; this output can also be programmed to indicate when the source is settled or output pulse video and is TTL and CMOS compatible in this mode; output impedance < 1 $\Omega$ , can drive 2 k $\Omega$ ; damage levels are $\pm$ 15 V
Ext 1	External AM/FM/PM #1 input; nominal input impedance is 50 $\Omega/600~\Omega/1M~\Omega,$ nominal; damage levels are $\pm$ 5 V
Ext 2	External AM/FM/PM #2 input; nominal input impedance is 50 $\Omega/600~\Omega$ /1M $\Omega,$ nominal; damage levels are $\pm$ 5 V
LF OUT	0 to 5 V peak into 50 Ω, –5 V to 5 V offset, nominal
Pulse	External pulse modulation input; this input is TTL and CMOS compatible; low logic levels are 0 V and high logic levels are $\pm 1$ V; nominal input impedance is 50 $\pm 1$ ; input damage levels are $\pm 1$ 0.3 V and $\pm 1$ 1.3 V

Trigger in	Accepts TTL and CMOS level signals for triggering point-to-point in sweep mode; damage levels are $\leq$ -0.3 V and $\geq$ +5.3 V
Trigger out	Outputs a TTL and CMOS compatible level signal for use with sweep mode The signal is high at start of dwell, or when waiting for point trigger in manual sweep mode, and low when dwell is over or point trigger is received This output can also be programmed to indicate when the source is settled, pulse synchronization, or pulse video Nominal output impedance 50 $\Omega$ Input damage levels are $\leq$ –0.3 V and $\geq$ +5.3 V
Reference input	Accepts a 10 MHz reference signal used to frequency lock the internal timebase; Option 1ER adds the capability to lock to a frequency from 1 MHz to 50 MHz; nominal input level $-3.5$ to $+20$ dBm, impedance $50$ $\Omega$ , sine or square waveform
10 MHz out	Outputs the 10 MHz reference signal used by internal timebase; level nominally +3.9 dBm; nominal output impedance 50 $\Omega$ ; input damage level is +16 dBm
LO in (Option 012)	Accepts a signal from a master signal generator that is used as the LO for EXG vector in order to configure a phase coherent system; nominal input levels between 0 to +7 dBm; nominal input impedance 50 $\Omega$
LO out (Option 012)	Outputs a reference signal that can be used in a phase coherent system; nominal output levels between 0 to 7 dBm; nominal output impedance 50 $\Omega$
Digital bus I/O	To be used with PXB or N5102A digital signal interface module
Aux IO	50 pin SCSI II connector; the AUX I/O connector provides additional digital signal inputs/outputs with Event 1 - 4 (Pin 1 - 4)  This connector outputs programmable timing signals generated by Markers 1 – 4; the marker signals can also routed internally to control the RF blanking and ALC hold functions  This output is TTL and 3.3 V CMOS compatible; damage levels are $> +8$ V and $< -4$ V
USB 2.0	The USB connector provides remote programming functions via SCPI
LAN (1000 BaseT)	The LAN connector provides the same SCPI remote programming functionality as the GPIB connector and is also used to access the internal Web server and FTP server Supports DHCP, sockets SCPI, VXI-11 SCPI, connection monitoring, dynamic hostname services, TCP keep alive LXI class C compliant  Trigger response time for the immediate LAN trigger is 0.5 ms (minimum), 4 ms (maximum), 2 ms, typical; delayed/alarm triger is unknown  Trigger output response time is 0.5 ms (minimum), 4 ms (maximum), 2 ms, typical
GPIB	The GPIB connector provides remote programming functionality via SCPI

### Related Literature

#### **Agilent X-Series Signal Generators**

EXG Configuration Guide 5990-9958EN

MXG Data Sheet 5991-0038EN

*MXG Configuration Guide* 5990-9959EN

X-Series Signal Generator Brochure 5990-9957EN

Signal Studio Software Brochure 5989-6448EN



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#### www.lxistandard.org

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